



300mA CMOS LDO

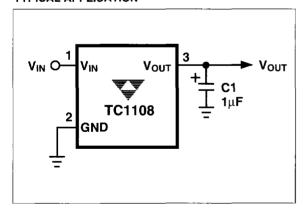
FEATURES

- Zero Ground Current for Longer Battery Life!
- Very Low Dropout Voltage
- Guaranteed 300mA Output
- High Output Voltage Accuracy
- Standard or Custom Output Voltages
- Over-Current and Over-Temperature Protection

APPLICATIONS

- Battery-Operated Systems
- Portable Computers
- Medical Instruments
- Instrumentation
- Cellular / GSM / PHS Phones
- Linear Post-Regulator for SMPS
- Pagers

TYPICAL APPLICATION



GENERAL DESCRIPTION

The TC1108 is a fixed output, high accuracy (typically $\pm 0.5\%$) CMOS low dropout regulator. Total supply current is typically $50\mu A$ at full load (20 to 60 times lower than in bipolar regulators!).

TC1108 key features include ultra low noise, very low dropout voltage (typically 240 mV at full load), and fast response to step changes in load. The TC1108 incorporates both over-temperature and over-current protection. The TC1108 is stable with an output capacitor of only $1\mu F$ and has a maximum output current of 300mA. It is available in a SOT-223 package.

ORDERING INFORMATION

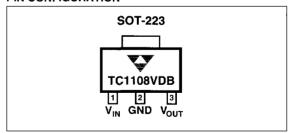
Part Number	Package	Junction Temp. Range	
TC1108-xxVDB	SOT-223	- 40°C to +125°C	
TC1015EV Eva	luation Kit for Cl	MOS I DO Family	

Available Output Voltages:

2.5, 2.8, 3.0, 3.3, 5.0

Other output voltages are available. Please contact TelCom Semiconductor for details,

PIN CONFIGURATION



TC1108

ABSOLUTE MAXIMUM RATINGS*

Input Voltage	7V
Output Voltage	$(V_{SS} - 0.3)$ to $(V_{IN} + 0.3)$
Power Dissipation	Internally Limited (Note 7)
Operating Temperature	– 40°C < T _J < 125°C
Storage Temperature	65°C to +150°C
Maximum Voltage on Any Pin	V _{IN} + 0.3V to - 0.3V
Lead Temperature (Soldering,	10 Sec.)+260°C

*Absolute Maximum Ratings indicate device operation limits beyond damage may occur. Device operation beyond the limits listed in Electrical Characteristics is not recommended.

ELECTRICAL CHARACTERISTICS: V_{IN} ≈ V_{OUT} + 1V, I_L = 100µA, C_L = 3.3µF, T_A ≈ 25°C, unless otherwise specified. **BOLDFACE** type specifications apply for junction temperatures of – 40°C to +125°C.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
V _{IN}	Input Operating Voltage		_		6.5	V
IOUTMAX	Maximum Output Current		300	_		mA
V _{OUT}	Output Voltage	Note 1	— V _R – 2.5%	V _R ± 0.5%	 V _R + 2.5%	V
ΔV _{OUT} /ΔΤ	V _{OUT} Temperature Coefficient	Note 2		40	_	ppm/°C
$\Delta V_{OUT}/\Delta V_{IN}$	Line Regulation	$(V_R + 1V) \le V_{IN} \le 6V$		0.05	0.35	%/V
ΔV _{OUT} /V _{OUT}	Load Regulation	I _L = 0.1mA to I _{OUTMAX} (Note 3)		0.5	2.0	%
V _{IN} – V _{OUT}	Dropout Voltage	I _L = .1mA I _L = 100mA I _L = 300mA (Note 4)		20 80 240	30 160 480	mV
IDD	Supply Current			50	90	μА
PSRR	Power Supply Rejection Ratio	F _{RE} ≤ 1kHz		60		dB
I _{OUTSC}	Output Short Circuit Current	V _{OUT} = 0V		550	650	mA
ΔV _{OUT} /ΔP _D	Thermal Regulation	Note 5		0.04	_	%/W
eN	Output Noise	$F = 1kHz$, $C_{OUT} = 1\mu F$, $R_{LOAD} = 50\Omega$	_	1		μV/√Hz

NOTES: 1. V_R is the regulator output voltage setting.

- 2. $T_C V_{OUT} = (V_{OUTMAX} V_{OUTMIN}) \times 10^{-6}$ Vout x DT
- 3. Regulation is measured at a constant junction temperature using low duty cycle pulse testing. Load regulation is tested over a load range from 0.1mA to the maximum specified output current. Changes in output voltage due to heating effects are covered by the thermal regulation specification.
- 4. Dropout voltage is defined as the input to output differential at which the output voltage drops 2% below its nominal value measured at a
- 5. Thermal Regulation is defined as the change in output voltage at a time T after a change in power dissipation is applied, excluding load or line regulation effects. Specifications are for a current pulse equal to I_{LMAX} at V_{IN} = 6V for T = 10msec.
- 6. The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature, and the thermal resistance from junction-to-air (i.e. T_A, T_J, q_{JA}). Exceeding the maximum allowable power dissipation causes the device to initiate thermal shutdown. Please see Thermal Considerations section of this data sheet for more details.

DETAILED DESCRIPTION

The TC1108 is a precision, fixed output LDO. Unlike bipolar regulators, the TC1108 supply current does not increase with load current. In addition, V_{OUT} remains stable and within regulation at very low load currents (an important consideration in RTC and CMOS RAM battery backup applications). Figure 1 shows a typical application circuit.

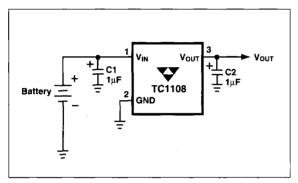


Figure 1: Typical Application Circuit

Output Capacitor

A $1\mu F$ (min) capacitor from V_{OUT} to ground is recommended. The output capacitor should have an effective series resistance of 5Ω or less, and a resonant frequency above 1MHz. A $1\mu F$ capacitor should be connected from V_{IN} to GND if there is more than 10 inches of wire between the regulator and the AC filter capacitor, or if a battery is used as the power source. Aluminum electrolytic or tantalum capacitor types can be used. (Since many aluminum electrolytic capacitors freeze at approximately $-30^{\circ}C$, solid tantalums are recommended for applications operating below $-25^{\circ}C$.) When operating from sources other than batteries, supplynoise rejection and transient response can be improved by increasing the value of the input and output capacitors and employing passive filtering techniques.

Thermal Considerations

Thermal Shutdown

Integrated thermal protection circuitry shuts the regulator off when die temperature exceeds 150°C. The regulator remains off until the die temperature drops to approximately 140°C.

Power Dissipation

The amount of power the regulator dissipates is primarily a function of input and output voltage, and output current. The following equation is used to calculate worst case *actual* power dissipation:

$$P_D \approx (V_{INMAX} - V_{OUTMIN})I_{LOADMAX}$$

Where: P_D = worst case actual power dissipation

V_{INMAX} = maximum voltage on V_{IN}

 V_{OUTMIN} = minimum regulator output voltage

I_{LOADMAX} = maximum output (load) current

Equation 1.

The maximum allowable power dissipation (Equation 2) is a function of the maximum ambient temperature (T_{AMAX}), the maximum allowable die temperature ($125^{\circ}C$) and the thermal resistance from junction-to-air (θ_{JA}).

$$P_{DMAX} = \frac{(T_{JMAX} - T_{AMAX})}{\theta_{JA}}$$

Where all terms are previously defined.

Equation 2.

Table 1 shows various values of θ_{JA} for the TC1108 mounted on a 1/16 inch, 2-layer PCB with 1 oz. copper foil.

Table 1. Thermal Resistance Guidelines for TC1108

Copper Area (Topside)*	Copper Area (Backside)	Board Area	Thermal Resistance (θ _{JA})
2500 sq mm	2500 sq mm	2500 sq mm	45°C/W
1000 sq mm	2500 sq mm	2500 sq mm	45°C/W
225 sq mm	2500 sq mm	2500 sq mm	53°C/W
100 sq mm	2500 sq mm	2500 sq mm	59°C/W
1000 sq mm	1000 sq mm	1000 sq mm	52°C/W
1000 sq mm	0 sq mm	1000 sq mm	55°C/W

NOTES: *Tab of device attached to topside copper

Equation 1 can be used in conjunction with Equation 2 to ensure regulator thermal operation is within limits. For example:

GIVEN: $V_{INMAX} = 3.3V \pm 10\%$

 $V_{OUTMIN} = 2.7V \pm 0.5\%$

 $I_{LOAD} = 275 \text{mA}$

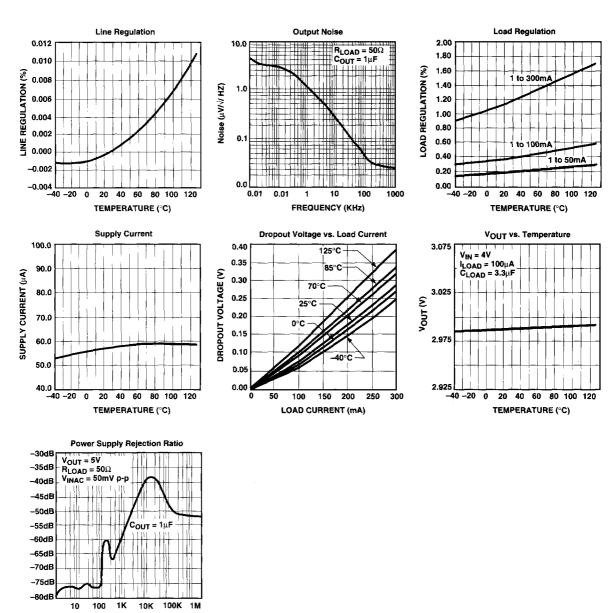
 $T_{AMAX} = 95^{\circ}C$

 $\theta_{JA} = 59^{\circ}C/W$

FIND: 1. Actual power dissipation

2. Maximum allowable dissipation

TYPICAL CHARACTERISTICS



FREQUENCY (KHz)

Actual power dissipation:

$$P_D \approx (V_{INMAX} - V_{OUTMIN})|_{LOADMAX}$$

= [(3.3 x 1.1) - (2.7 x .995)]275 x 10⁻³
= 260mW

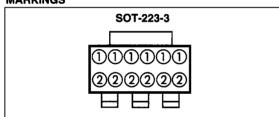
Maximum allowable power dissipation:

$$\mathsf{PD}_{\mathsf{MAX}} = \frac{(\mathsf{T}_{\mathsf{JMAX}} - \mathsf{T}_{\mathsf{AMAX}})}{\theta_{\mathsf{JA}}}$$

= <u>508mW</u>

In this example, the TC1108 dissipates a maximum of only 260mW; far below the allowable limit of 508mW. In a similar manner, Equation 1 and Equation 2 can be used to calculate maximum current and/or input voltage limits. For example, the maximum allowable V_{IN} is found by substituting the maximum allowable power dissipation of 508mW into Equation 1, from which $V_{INMAX} = 4.6V$.

MARKINGS



- 1) part number code + temperature range and voltage
- 2) represents date

TC1108 (V)	Code
TC1108-2.5VDB	110825
TC1108-2.8VDB	110828
TC1108-3.0VDB	110830
TC1108-3.3VDB	110833
TC1108-5.0VDB	110850

